

SN54AHC16540, SN74AHC16540 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCLS331 – MARCH 1996

- Members of the Texas Instruments **Widebus™** Family
- Operating Range 2-V to 5.5-V V_{CC}
- **EPIC™** (Enhanced-Performance Implanted CMOS) Process
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

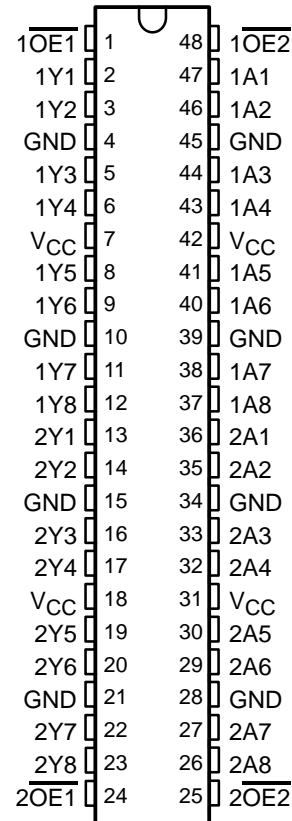
These 16-bit buffers and bus drivers provide a high-performance bus interface for wide data paths.

The 3-state control gate is a 2-input AND gate with active-low inputs so that if either output-enable ($\overline{OE1}$ or $\overline{OE2}$) input is high, all corresponding outputs are in the high-impedance state.

The SN74AHC16540 is available in TI's shrink small-outline (DL) and thin shrink small-outline (DGG) packages, which provide twice the I/O pin count and functionality of standard small-outline packages in the same printed-circuit-board area.

The SN54AHC16540 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74AHC16540 is characterized for operation from -40°C to 85°C .

SN54AHC16540 . . . WD PACKAGE
SN74AHC16540 . . . DGG OR DL PACKAGE
(TOP VIEW)



FUNCTION TABLE
(each 8-bit section)

INPUTS			OUTPUT Y
$\overline{OE1}$	$\overline{OE2}$	A	
L	L	L	H
L	L	H	L
H	X	X	Z
X	H	X	Z



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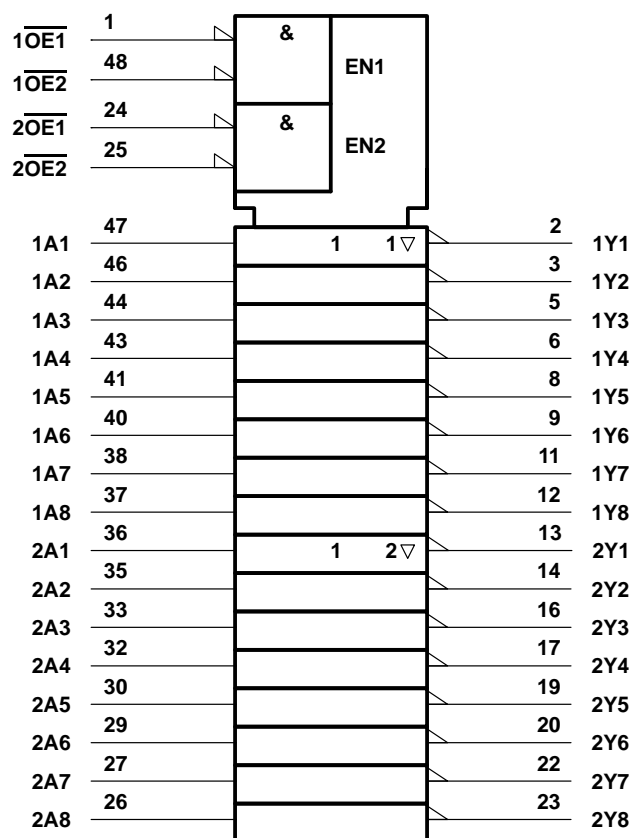
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16-BIT BUFFERS/DRIVERS

WITH 3-STATE OUTPUTS

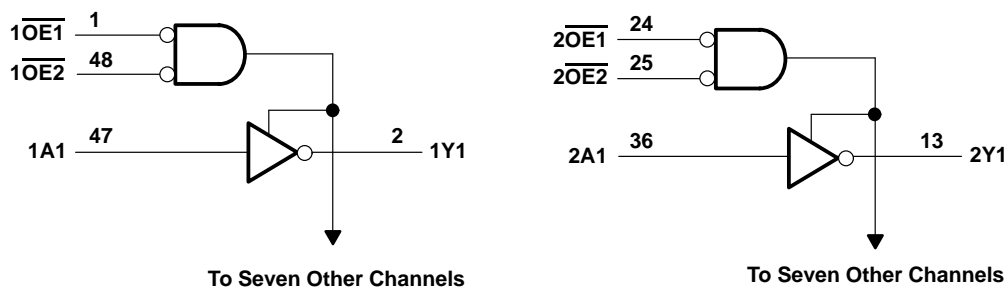
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logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (see Note 1)	–0.5 V to 7 V
Output voltage range, V_O (see Note 1)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	–20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through each V_{CC} or GND	±75 mA
Maximum power dissipation at $T_A = 55^\circ\text{C}$ (in still air) (see Note 2): DGG package	0.85 W
DL package	1.2 W
Storage temperature range, T_{stg}	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.

recommended operating conditions (see Note 3)

			SN54AHC16540		SN74AHC16540		UNIT
			MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage		2	5.5	2	5.5	V
V_{IH}	High-level input voltage	$V_{CC} = 2$ V	1.5		1.5		V
		$V_{CC} = 3$ V	2.1		2.1		
		$V_{CC} = 5.5$ V	3.85		3.85		
V_{IL}	Low-level input voltage	$V_{CC} = 2$ V		0.5		0.5	V
		$V_{CC} = 3$ V		0.9		0.9	
		$V_{CC} = 5.5$ V		1.65		1.65	
V_I	Input voltage		0	5.5	0	5.5	V
V_O	Output voltage		0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current	$V_{CC} = 2$ V		–50		–50	µA
		$V_{CC} = 3.3 \pm 0.3$ V		–4		–4	mA
		$V_{CC} = 5 \pm 0.5$ V		–8		–8	
I_{OL}	Low-level output current	$V_{CC} = 2$ V		50		50	µA
		$V_{CC} = 3.3 \pm 0.3$ V		4		4	mA
		$V_{CC} = 5 \pm 0.5$ V		8		8	
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 3.3 \pm 0.3$ V		100		100	ns/V
		$V_{CC} = 5 \pm 0.5$ V		20		20	
T_A	Operating free-air temperature		–55	125	–40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			SN54AHC16540		SN74AHC16540		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V _{OH}	I _{OH} = -50 µA	2 V	1.9	2		1.9		1.9		V
		3 V	2.9	3		2.9		2.9		
		4.5 V	4.4	4.5		4.4		4.4		
	I _{OH} = -4 mA	3 V	2.58			2.48		2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		
V _{OL}	I _{OL} = 50 µA	2 V			0.1		0.1		0.1	V
		3 V			0.1		0.1		0.1	
		4.5 V			0.1		0.1		0.1	
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
I _I	Data inputs	V _I = V _{CC} or GND	5.5 V		±0.1		±1		±1	µA
	Control inputs				±0.1		±1		±1	
I _{OZ} [†]	V _O = V _{CC} or GND, V _I ($\overline{\text{OE}}$) = V _{IL} or V _{IH}	5.5 V			±0.25		±2.5		±2.5	µA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5 V			4		40		40	µA
C _i	V _I = V _{CC} or GND	5 V		2	10				10	pF
C _o	V _O = V _{CC} or GND	5 V		4						pF

[†] The parameter I_{OZ} includes the input leakage current.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V ±0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			SN54AHC16540		SN74AHC16540		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{PLH} *	A	Y	C _L = 15 pF		4.8	7	1	8.5	1	8.5	ns
t _{PHL} *					4.8	7	1	8.5	1	8.5	
t _{PZH} *	$\overline{\text{OE}}$	Y	C _L = 15 pF		6.8	10.5	1	12.5	1	12.5	ns
t _{PZL} *					6.8	10.5	1	12.5	1	12.5	
t _{PHZ} *	$\overline{\text{OE}}$	Y	C _L = 15 pF		6.8	10.5	1	12.5	1	12.5	ns
t _{PLZ} *					6.8	10.5	1	12.5	1	12.5	
t _{PLH}	A	Y	C _L = 50 pF		7.3	10.5	1	12	1	12	ns
t _{PHL}					7.3	10.5	1	12	1	12	
t _{PZH}	$\overline{\text{OE}}$	Y	C _L = 50 pF		8	14	1	16	1	16	ns
t _{PZL}					8	14	1	16	1	16	
t _{PHZ}	$\overline{\text{OE}}$	Y	C _L = 50 pF		8	15.4	1	17.5	1	17.5	ns
t _{PLZ}					8	15.4	1	17.5	1	17.5	

* On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

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switching characteristics over recommended operating free-air temperature range, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN54AHC16540		SN74AHC16540		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}^*	A	Y	$C_L = 15\text{ pF}$		3.7	5	1	6	1	6	ns
t_{PHL}^*					3.7	5	1	6	1	6	
t_{PZH}^*	\overline{OE}	Y	$C_L = 15\text{ pF}$		4.7	7.2	1	8.5	1	8.5	ns
t_{PZL}^*					4.7	7.2	1	8.5	1	8.5	
t_{PHZ}^*	\overline{OE}	Y	$C_L = 15\text{ pF}$		4.5	6.8	1	8	1	8	ns
t_{PLZ}^*					4.5	6.8	1	8	1	8	
t_{PLH}	A	Y	$C_L = 50\text{ pF}$		5.2	7	1	8	1	8	ns
t_{PHL}					5.2	7	1	8	1	8	
t_{PZH}	\overline{OE}	Y	$C_L = 50\text{ pF}$		6.2	9.2	1	10.5	1	10.5	ns
t_{PZL}					6.2	9.2	1	10.5	1	10.5	
t_{PHZ}	\overline{OE}	Y	$C_L = 50\text{ pF}$		6	8.8	1	10	1	10	ns
t_{PLZ}					6	8.8	1	10	1	10	

* On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

output-skew characteristics, $C_L = 50\text{ pF}$ (see Note 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	SN74AHC16540				UNIT
				T _A = 25°C		MIN	MAX	
				MIN	MAX			
t _{sk(o)}	A	Y	3.3 V ±0.3 V	1.5		1.5		ns
			5 V ±0.5 V	1		1		

NOTE 4: Characteristics are determined during product characterization and ensured by design.

noise characteristics, $V_{CC} = 5\text{ V}$, $C_L = 50\text{ pF}$, $T_A = 25^\circ\text{C}$ (see Note 5)

PARAMETER		SN74AHC16540			UNIT
		MIN	TYP	MAX	
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}			0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}			-0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}	4.7			V
$V_{IH(D)}$	High-level dynamic input voltage	3.5			V
$V_{IL(D)}$	Low-level dynamic input voltage			1.5	V

NOTE 5: Characteristics are determined during product characterization and ensured by design for surface-mount packages only.

operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C_{pd} Power dissipation capacitance	No load, $f = 1\text{ MHz}$	12	pF

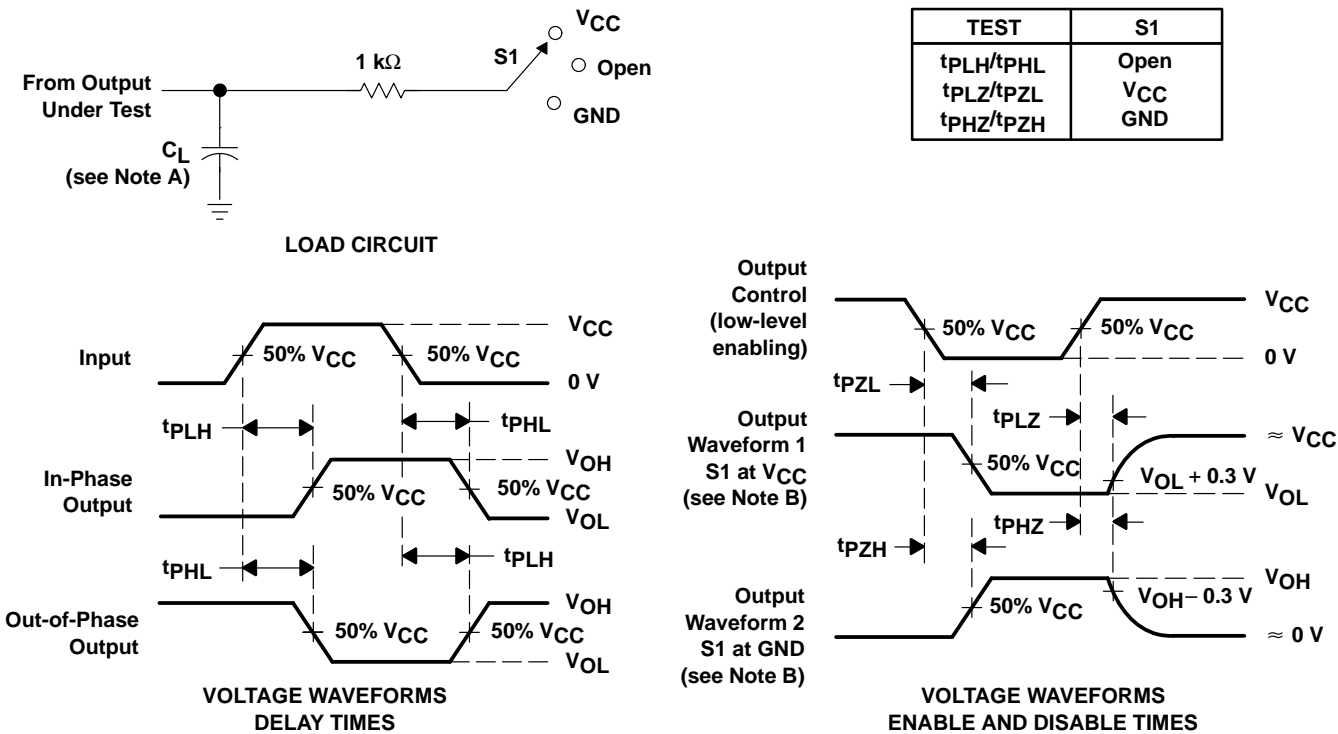
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PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r = 3 ns, t_f = 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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